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Highly Luminescent CdTe/CdSe Colloidal Heteronanocrystals with Temperature-Dependent Emission Color

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Abstract: In this work we present the preparation of highly luminescent anisotropic CdTe/CdSe colloidal heteronanocrystals. The reaction conditions used (low temperature, slow precursor addition, and surfactant composition) resulted in a tunable shape from prolate to branched CdTe/CdSe nanocrystals. Upon CdSe shell growth the heteronanocrystals show a gradual evolution from type-I to type-II optical behavior. These heteronanocrystals show a remarkably high photoluminescence quantum yield (up to 82%) and negligible thermally induced quenching up to temperatures as high as 373 K.

1. Introduction

The remarkable size and shape-dependent properties of semiconductor nanostructures¹ have attracted increasing interest over the past decades, and as a result, an excellent degree of control over the composition, size, shape, and surface of semiconductor nanocrystals has been achieved in recent years by using colloidal chemistry routes.² Semiconductor heteronanostructures, such as core/shell quantum dots (QDs), can show different behavior regarding charge carrier localization after photoexcitation (type-I or type-II), depending on the band offset alignments between the core and the shell materials.³ In type-I QDs both carriers are primarily confined in the same part of the heterostructure, while in type-II QDs the band offsets are such that electrons and holes are spatially separated, leading to the formation of an indirect exciton. The radiative recombination of the indirect exciton will result in emission at lower energies than those of both the core and the shell optical gaps, thus allowing access to wavelengths that would otherwise not be available with a single material or type-I QDs. Since the position of the energy levels of QDs is strongly size-dependent, 1,2 the relative energy offsets can be tuned by controlling the core diameter and the shell thickness. This offers the possibility of directly controlling the degree of charge carrier localization from

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type-I to type-II,⁴ and consequently the emission wavelength, exciton radiative lifetimes and the exciton confinement energies, with important consequences for a number of potential applications such as photovoltaic devices, photocatalysts, lasers, and LEDs.

The potential advantages of colloidal type-II QDs have triggered an increasing interest in the past few years, 4-17 and several semiconductor combinations have been investigated as prospective type-II QDs, based on the band offsets of the bulk materials (viz., ZnSe-CdSe,⁴⁻⁵ CdTe-CdSe,⁶⁻¹² ZnTe-CdSe^{6,13-15}). These pioneering studies⁴⁻¹⁷ have provided a wealth of new insights into both the chemistry and the physics of colloidal type-II QDs, but there are still several challenging issues to be addressed. For example, the photoluminescence quantum yields (QYs) reported for colloidal type-II QDs are

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typically very low $(0-10\%^{6,8,10-16})$. High QYs (30-40%) have been reported for thin shell heteronanocrystals of both CdTe/ CdSe and ZnTe/CdSe. 15,16 However, these thin shell heteronanocrystals still present a type-I character, as they do not show the featureless subband-gap absorption tail indicative of the spatially indirect transitions expected for type-II QDs.^{6,10} With increasing shell thickness the long absorption tail appears but the transition from type-I to type-II behavior is accompanied by a strong decrease in QY to below 10%. These low QYs have been seen as an intrinsic limitation of type-II QDs,^{6,12} since the slower radiative recombination of indirect excitons would facilitate the dominance of nonradiative recombination at defects. However, preparation methodologies that minimize both surface and interfacial defects may substantially improve the photoluminescence QYs of type-II QDs beyond its low current values. Accordingly, a recent report describes highly luminescent CdS/ZnSe core/shell type-II nanocrystals with emission QYs up to 50% that benefit from an intermediate ZnCdSe alloy layer with a graded composition.¹⁷ Here we describe the synthesis and properties of highly luminescent CdTe/CdSe core/shell nanocrystals (NCs). The synthesis method developed in this work yields highly efficient (PL QY up to 80% at 300 K) anisotropic CdTe/CdSe core/shell NCs, with shapes tunable from prolate type-I QDs (aspect ratio: 1.5-2) to branched heteronanocrystals that exhibit type-II character. The high quality of these CdTe/CdSe heteronanocrystals is also attested by the negligible contribution of thermally induced luminescence quenching processes in the 293-383 K temperature range, allowing the temperature dependence of the emission color to be observed. The results reported here clearly demonstrate that type-II heteronanocrystals can have high photoluminescence QYs, despite the longer radiative lifetimes of indirect excitons.

2. Experimental Section

2.1. Chemicals. Trioctylphosphine (TOP, 90%), trioctylphosphine oxide (TOPO, 99%), dodecylamine (DDA, 98%), hexadecylamine (HDA, 90%), and anhydrous solvents (toluene, methanol, chloroform) were all purchased from Aldrich. Selenium powder (99.99%, 200 mesh) and anhydrous cadmium acetate (CdAc, 99.99+%) were purchased from Chempur. Tellurium powder (99.999%, <250 µm) and dimethylcadmium (99.99%) were purchased from Heraeus and ARC Technologies, respectively. All chemicals were used as received, with the exception of TOPO, HDA, and DDA, which were dried and degassed before use by heating under vacuum, DDA at 373 K for 6 h, TOPO and HDA at 393 K for 1.5 h.

2.2. Synthesis and Experimental Details. High-quality greenemitting CdTe QDs (2.6-2.8 nm average diameter, 5-10% size dispersion) were prepared in DDA/TOP following a previously reported method¹⁸ and subsequently purified by filtration (to remove unreacted Te), precipitation with anhydrous methanol, and drying under vacuum. The purified CdTe QDs (16 mg) were dissolved in toluene (1 mL) and redispersed in a TOPO (67 wt %)-HDA (33 wt %) mixture at 393 K. Previous work has shown that this surfactant mixture allows wellcontrolled growth and yields high-quality CdSe QDs.¹⁹ The CdSe shell growth is carried out at 423 K by dropwise (0.05 mL/min) and alternate addition of Cd (0.86 mmol of CdAc in 3 mL of TOP) and Se (1.26 mmol of Se in 3 mL of TOP) precursors, followed by a 30 min annealing step at 403 K. Aliquots of the growth solution (Table 1) were taken at regular time intervals during the shell growth and quickly

Table 1. CdTe/CdSe Samples Isolated during Shell Growtha

sample t (min)				CdSe shell thickness (nm)	
	λ_{max} (nm)	QY (%)	length direction	diameter direction	
core		535	7		
A	5	539	34	0.2^{b}	
В	15	585	46	0.66	0.1
C	30	630	82	0.92	0.2
D	45	711	52	1.6^{c}	
E	90	789	45	$6-10^d$	3^d

^a Reaction time (t), photoluminescence maximum (λ_{max}), and quantum yield (QY). CdSe thickness along the particle length and diameter directions. ^bTips. ^cDiagonal direction assuming that the CdTe core occupies the center of the pyramids. ^dBranch length and diameter.

cooled into room-temperature decalin. No postpreparative procedure was employed after sampling, except for the samples to be investigated by transmission electron microscopy, which were purified by precipitation with anhydrous methanol. All optical measurements were carried out on samples with a low optical density (≤ 0.1 at the excitation wavelength). Absorption and PL spectra were collected with a Perkin-Elmer Lambda 900 spectrophotometer and an Edinburgh Instruments FS920 spectrophotometer, respectively. PL quantum yields were determined using fluorescein in 0.1 M NaOH20 and rhodamine 101 in 0.01% HCl ethanolic solution21 as references, following the method reported in ref 19. Lifetime measurements were carried out using timecorrelated single photon counting (TCSPC). The nanocrystal dispersions were excited at 400 nm using a picosecond diode laser (PicoQuant PDL 800B) operated at 0.5-2.5 MHz. The detector unit consisted of a Peltier-cooled Hamamatsu microchannel plate photomultiplier (R3809U-50). TEM and high-resolution TEM were performed on a TECNAI G² 20 transmission electron microscope (FEI Co., The Netherlands) operated at 200 kV or on a Titan Krios transmission electron microscope (FEI Co., The Netherlands) operated at 300 kV. The samples for TEM were prepared by dipping a carbon-coated copper (400-mesh) TEM grid into a chloroform solution of nanocrystals. The excess liquid was removed by blotting using filter paper.

3. Results and Discussion

3.1. CdTe/CdSe Heteronanocrystal Growth. The alternate addition of low reactivity precursors (such as cadmium oleate or cadmium acetate) prevents homogeneous nucleation, as has been demonstrated by several recent works employing the SILAR (Successive Ion Layer Adsorption and Reaction) approach²² to prepare core-shell QDs^{7,15,22} and core-multishell QDs²³⁻²⁶ (e.g., CdSe-CdS-(Cd,Zn)S-ZnS,²³ CdS-CdSe-CdS^{24,26}). In contrast to the standard SILAR technique, which is based on alternate injections of enough precursors to yield one monolayer of the cation or anion, 22-26 in the present work the alternate addition of precursors is carried out dropwise, thus making homogeneous nucleation even more unlikely. The low growth temperature further decreases the reactivity of the precursors, ensuring that heterogeneous nucleation and growth of CdSe at the surface of the CdTe nanocrystals prevails, and also prevents growth of the CdTe cores by Ostwald ripening¹⁸ or alloying

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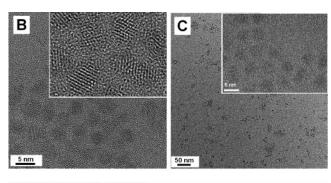
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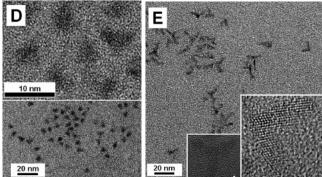


Figure 1. Overview TEM images of CdTe/CdSe heteronanocrystal samples B-E (see Table 1) collected at different stages during the CdSe shell growth. Insets show corresponding HRTEM images.

due to interdiffusion.²⁷ Therefore, any change in the size (or shape) of the nanocrystals can be ascribed to the shell growth.

As a representative example, Figure 1 shows TEM images of samples collected at different stages during the CdSe shell growth on spherical CdTe cores with a diameter of 2.6 nm (5% size dispersion). It can be seen that the growth is highly anisotropic, initially yielding prolate heteronanocrystals (Figure 1, sample B, diameter: 2.7 nm; length: 3.9 nm, implying the growth of 0.66 nm CdSe "tips" in the length direction only), which evolve in trigonal pyramids (Figure 1, sample D, side length: 5.2 nm, implying a 1.6 nm CdSe shell under the assumption that the CdTe core occupies the center of the pyramids) and eventually undergo branching producing multipods (Figure 1, sample E; mostly bipods, but tripods, rods, matchsticks, and more complex multibranched shapes are also present; branch diameter: 3 nm; branch length: 6-10 nm).

The anisotropic growth can be understood considering the set of reaction conditions used in this work (viz., low reactivity precursors, low reaction temperature, slow precursor addition, coordinating solvent with higher affinity for Cd than for Se). Under these conditions the CdSe heteroepitaxial growth is slow and kinetically controlled (i.e., the rate-limiting step is the CdSe formation at the surface, rather than the diffusion of precursors), and therefore the higher reactivity of the {0001} Se terminated polar facets of the CdSe wurtzite structure will favor anisotropic growth along the c-direction. ^{28–31} The growth evolution toward branched heterostructures, such as the CdTe/CdSe bipods and tripods shown in Figure 1 for sample E, is probably due to the

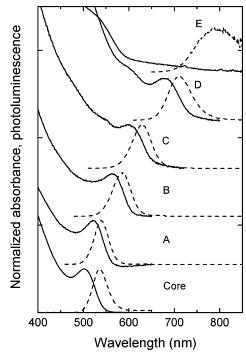


Figure 2. Absorption (solid lines) and photoluminescence (dashed lines) spectra of colloidal CdTe/CdSe heteronanocrystals with a 2.6 nm CdTe core and increasing CdSe shell dimension. Labels correspond to Table 1. Spectra are shifted vertically for clarity.

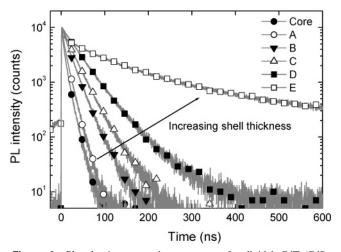


Figure 3. Photoluminescence decay curves of colloidal CdTe/CdSe heteronanocrystals with a 2.6 nm CdTe core and increasing CdSe shell dimensions (labels are explained in Table 1). The decay curve of the CdTe QDs used as cores is also shown (Core).

different crystal structures of the CdTe core (zincblende) and the growing CdSe shell (wurtzite) (see Supporting Information for XRD data). 10,28

3.2. Optical Properties: Absorption, Photoluminescence, Quantum Yields, and Exciton Lifetimes. Figures 2 and 3 show that the optical properties (viz., absorption, photoluminescence, and exciton lifetimes) of the CdTe/CdSe heteronanocrystals change dramatically during the CdSe "shell" growth. The emission wavelength red shifts from 535 nm (2.32 eV) for the CdTe cores (Figure 2) to 770 nm (1.61 eV) for the CdTe/CdSe multipods (sample E in Figures 1-3 and Table 1). The absorption also red shifts, but as the dimension of the CdSe part of the heteronanocrystal increases, the absorption features are smeared out and the oscillator strengths at the emission

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energies become relatively smaller (Figure 2), while the RT photoluminescence decay times (i.e., the exciton lifetimes) become longer (Figure 3). The increase in the exciton lifetime observed for sample CdTe/CdSe B (18 ns, 1-exponential decay; Figure 3) with respect to the CdTe cores (multiexponential decay, average lifetime: 8 ns; Figure 3) is mostly due to the decrease of the nonradiative decay rates, since it is accompanied by a substantial increase in the PL QYs (viz., from 7% to 46%, Table 1). Moreover, the radiative exciton lifetime for CdTe QDs of similar size (viz., 3.0 nm) has been reported to be 18 ns.³² Further growth of the CdSe part leads to increasingly longer exciton lifetimes and a change from singleexponential to biexponential decay (viz., Sample C: 24 ns, 1-exp. decay; Sample E: 2-exp. decay, 60 and 220 ns, average lifetime: 100 ns). The faster component of the biexponential decay is attributed to CdTe/CdSe heteronanocrystals in which nonradiative exciton recombination is also relevant, while the slower component is attributed to purely radiative decay. It is worth noting that the featureless absorption tail observed for the CdTe/CdSe multipods (Figure 2, sample E) is at lower energy than the band edge absorption of both the CdTe core (see Figure 2) and the CdSe branches (565 nm for CdSe nanorods with 3.2 nm diameter and 11 nm length^{33–34}). Therefore both the absorption tail and the photoluminescence peak can be unambiguously assigned to an indirect exciton.

These results indicate a progressive reduction of the electron hole wave function overlap and the formation of an indirect exciton as the dimension of the CdSe part of the heteronanocrystal increases (reflected in the progressively longer lifetimes accompanied by a spectral red shift and the development of a featureless subband-gap absorption tail), ultimately leading to a characteristic type-II behavior^{3-6,9} for the CdTe/CdSe multipods (sample E). The gradual evolution of semiconductor heteronanocrystals toward a type-II optical behavior has been demonstrated for ZnSe/CdSe,4-5 CdTe/CdSe,6-9 and CdS/ ZnSe¹⁷ spherical core/shell heteronanocrystals and observed to depend on both the core diameter and the shell thickness. This is consistent with the fact that the position of the energy levels of semiconductor nanostructures is strongly size-dependent, 1,2 making the relative energy offsets and the degree of carrier localization in heteronanocrystals strongly sensitive to the dimensions (and shape) of both the core and the shell.^{9,17,35} Recent theoretical modeling of ZnSe/CdSe³⁵ and CdS/ZnSe¹⁷core/shell nanocrystals has shown that the carrier localization regime becomes dependent on the core diameter and shell thickness in the case of small core diameters, evolving from type-I to type-II through an intermediate regime ("quasi-type-II"), in which one carrier is still delocalized over the entire volume of the heteronanocrystal. Calculations based on the effective mass approximation have also been carried out for a CdTe/CdSe core/shell system⁹ (core diameter: 3.9 nm) and show that the hole wave function is mostly localized in the core already for rather thin CdSe shells (0.2 nm), while the electron wave function remains delocalized through the whole core/shell QD up to a shell thickness of 0.9 nm, when it starts to localize in the shell. The transition from type-I to type-II behavior is thus not abrupt, leading to a gradual change in the optical properties as the localization of the electron and hole in different parts of the heteronanostructure becomes more pronounced, in good qualitative agreement with the results reported here. The use of the theoretical models above 9,17,35 to quantitatively analyze our results is precluded by the fact that the heteronanocrystals are modeled in refs 9, 17, and 35 as spherically symmetric core/shell nanostructures.

Low PL QYs have been seen as an intrinsic limitation of type-II heteronanostructures, since the slower radiative recombination of indirect excitons should facilitate the dominance of nonradiative recombination.^{6,12} In this context the high PL quantum yields of the CdTe/CdSe heteronanocrystals investigated here (as high as 82% for prolate nanocrystals and 45% for multipods dispersed in chloroform, see Figure 2) are extremely remarkable, since they are in striking contrast with the extremely low PL QYs reported in the literature for CdTe/ CdSe nanostructures, viz. $\leq 10\%$ for core/shell QDs^{6,8,16} and \sim 0% for tetrapods, ¹⁰ heteronanorods, ¹¹ and dumbbarbells. ¹² These high PL QYs indicate relatively slow nonradiative recombination rates, implying low defect concentrations and therefore attesting the high-quality of the CdTe/CdSe heteronanocrystals prepared in this work. The low defect concentration is probably due to the combination of slow heteroepitaxial growth and conditions that favor effective surface passivation, relaxation, and reconstruction. 18,19 An additional effect of the anisotropic growth is the smaller strain at the CdTe-CdSe heterointerfaces compared to spherical core/shell heteronanocrystals. The lattice mismatch between CdTe and CdSe (\sim 6%) will lead to defects in thick shell spherical nanocrystals, but anisotropic growth will minimize the stress in the heterostructured nanocrystal and reduce the formation of nonradiative traps, since anisotropic heteronanocrystals, such as heteronanorods, can accommodate much larger lattice mismatches than concentric heterostructures. 10 These results show that type-II heteronanocrystals can have high QYs, despite the longer radiative lifetimes of indirect excitons, provided the concentration of surface and interfacial defects is minimized.

3.3. Temperature Dependence of the Optical Properties.

Figure 4 presents the emission spectra of CdTe/CdSe heteronanocrystals (Figure 4a) and 2.6 nm CdTe QDs (Figure 4b) at several temperatures (293-383 K) and compares the temperature-dependent photoluminescence quantum vields of CdTe QDs and a number of CdTe/CdSe heteronanocrystal samples dispersed in decalin (Figure 4c). It can be seen that the PL intensity of CdTe QDs is strongly quenched as the temperature increases, while that of the CdTe/CdSe heteronanocrystals remains essentially unaffected (or even shows a modest increase in some cases). The different behavior of CdTe QDs and CdTe/ CdSe heteronanocrystals regarding thermally activated nonradiative relaxation is also reflected in the PL decay curves (Figure 5), which become faster and more nonexponential with increasing temperature for CdTe QDs (Figure 5a), consistent with an increasing contribution of nonradiative recombination to the exciton relaxation. In contrast, the PL decay curves of CdTe/ CdSe heteronanocrystals (see Figure 5b for a representative example) remain (nearly)single-exponential and become slightly slower with increasing temperature, which correlates well with the absence of thermal quenching and the modest increase in

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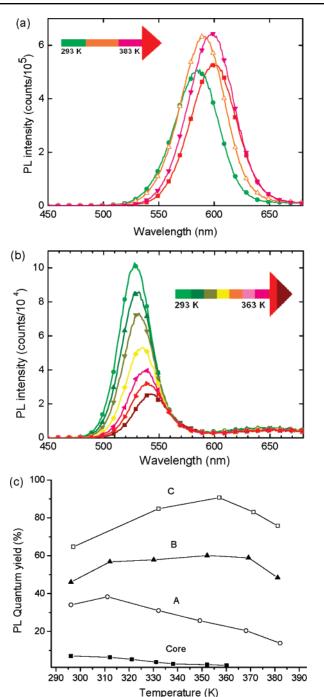


Figure 4. Photoluminescence spectra of (a) CdTe/CdSe heteronanocrystals (Sample B, Table 1) at temperatures between 293 and 383 K and (b) 2.6 nm CdTe QDs at temperatures between 293 and 363 K. (c) PL QY in decalin as a function of temperature for 2.6 nm CdTe QDs and prolate CdTe/CdSe samples (core and samples A, B, and C as in Table 1).

the luminescence QYs observed upon increasing the temperature from 293 to 373 K (Figure 4). Temperature quenching of the photoluminescence of QDs (e.g., CdSe/ZnS core/shell) is a commonly observed phenomenon, both in colloidal suspensions and in solvent-free systems, such as QDs embedded in polymeric matrices and QD solids, and is ascribed to thermally activated carrier trapping and nonradiative recombination at defects.^{36–39} The behavior of the CdTe/CdSe heteronanocrystals is thus quite

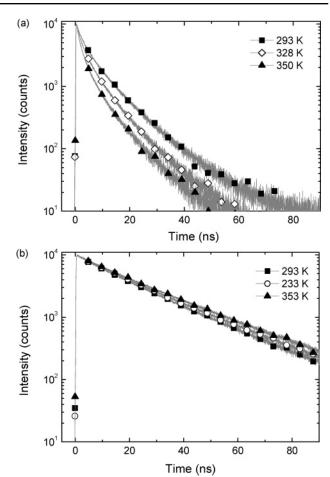


Figure 5. Photoluminescence decay of (a) CdTe QDs and (b) CdTe/CdSe QD (sample C) at different temperatures.

remarkable and unusual, indicating that the defect concentration in these nanocrystals is very low. The modest increase in the PL intensities accompanied by slightly longer exciton lifetimes suggests that the nonradiative recombination rates even decrease a little with increasing temperature. This behavior is reminiscent of the "luminescence temperature antiquenching" effect observed for CdSe QDs capped by linear alkylamines⁴⁰ and is probably also due to a reversible surfactant-assisted surface relaxation (and/or reconstruction).

Figure 4 shows also that the PL peak red shifts as the temperature increases, for both the CdTe cores and CdTe/CdSe heteronanocrystals. The data presented in Figure 6 reveal that this thermally induced PL red shift is larger for the CdTe cores and decreases as the dimension of the CdSe part of the heteronanocrystal increases. The absorption spectra are also observed to red shift with increasing temperature, but a quantitative analysis is complicated by the fact that the lowest energy absorption peak also contains contributions from the lower energy tail of higher energy transitions (the bands are quite broad with respect to the energy separation between subsequent transitions). Since different absorption transitions

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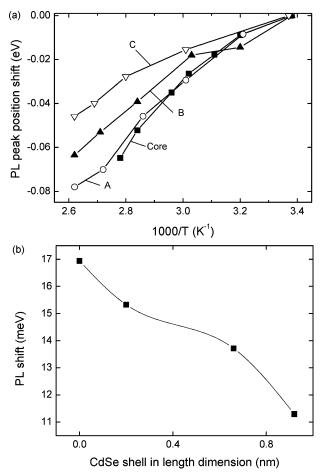


Figure 6. (a) PL peak position as function of temperature for CdTe and CdTe/CdSe heteronanocrystals with increasing prolate shell thickness (samples A, B, and C, as defined in Table 1). (b) Total PL emission shift from 293 to 373 K for CdTe/CdSe heteronanocrystals with increasing prolate CdSe shell.

may have different temperature dependences in terms of both energies and oscillator strengths, the maximum of the lowest absorption peak may not reliably reflect the temperature dependence of lowest energy exciton transition. The temperature-dependent shift of the absorption and the emission spectra (as well as the accompanying PL intensity changes discussed above) are fully reversible, indicating that the samples do not undergo any chemical modification and that the temperature dependence of the optical properties can be thus ascribed to a band gap change.

The temperature dependence of the band gap $(E_{\rm g})$ of bulk semiconductors is well described by the Varshni relation, ⁴¹ which has been shown to be also valid for semiconductor nanocrystals: ^{36,42}

$$E_{\rm g} = E_0 - \alpha \cdot T^2 / (T + \beta)$$

where α is the temperature coefficient, β is approximately the Debye temperature of the material, and E_0 is the band gap at 0 K. The values of α and β have been obtained for CdSe/ZnS nanocrystals [viz., (3.2 \pm 0.2) \times 10⁻⁴ eV/K and 220 \pm 30 K, ref 36 and (4.2 \pm 0.5) \times 10⁻⁴ eV/K and 155 \pm 55 K, ref 42,

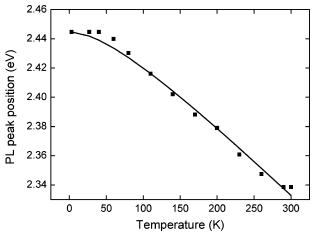


Figure 7. Photoluminescence peak position of 2.6 nm CdTe QDs as a function of temperature. The solid line is the best-fit curve with the Varshni relation

for α and β , respectively] and are consistent with the values known for bulk CdSe [*viz.*, $(2.8-4.1) \times 10^{-4}$ eV/K and $(181-4.1) \times 10^{-4}$ 315) K for α and β , respectively⁴³]. However, α and β values for CdTe nanocrystals are not available in the literature, and the values reported for bulk CdTe are conflicting (e.g., $\alpha =$ -3×10^{-4} eV/K in ref 44 and 4.1 $\times 10^{-4}$ eV/K in ref 45). Therefore, the α and β coefficients of CdTe nanocrystals were determined in this work, by fitting the Varshni relation to the temperature dependence of the PL peak positions of 2.6 nm CdTe QDs in the 3 to 280 K temperature range (Figure 7). The fit yields a band gap of 2.446 eV at 0 K, $\alpha = (5 \pm 0.47) \times$ 10^{-4} eV/K and $\beta = 102 \pm 32$ K, which is close to the Debye temperature (158 K) reported in literature. 43 These results imply that the band gap of CdTe depends more strongly on the temperature than that of CdSe, which explains the results reported above (Figure 6). As discussed above (section 3.2), the hole wave function is strongly localized in the CdTe core already for rather thin CdSe shells, while the electron wave function progressively localizes in the CdSe part of the heteronanocrystal as the CdSe dimensions increase. Consequently, the CdSe contribution to the PL energies becomes increasingly larger, leading to a smaller temperature-dependent shift of the PL peak.

4. Conclusions

In summary, the preparation methodology developed in this work yields highly efficient anisotropic CdTe/CdSe colloidal heteronanocrystals, with shapes tunable from prolate to branched heteronanocrystals. The high-quality and low defect concentration of these heteronanocrystals is attested by their high photoluminescence quantum yields and negligible thermally induced quenching up to temperatures as high as 373 K, which allowed the observation of reversible thermally induced spectral red shifts. A progressive reduction of the electron—hole wave function overlap and the formation of an indirect exciton are observed as the dimension of the CdSe part of the heteronanoc-

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rystal increases, ultimately leading to a characteristic type-II behavior for the CdTe/CdSe multipods. These results show that type-II heteronanostructures can have high photoluminescence quantum yields, which has important consequences for a number of potential applications (e.g., photovoltaic devices, lasers, LEDs).

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Supporting Information Available: X-ray powder diffraction of CdTe and CdTe/CdSe QDs. This material is available free of charge via the Internet at http://pubs.acs.org.

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